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Large-scale preparation of shape controlled SnO and improved capacitance for supercapacitor: From nanocluster to square microplate

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Fig. S1 TGA curves of U-SnO and UH-SnO.



Fig. S2 (a) Nitrogen adsorption and desorption isotherms at 77 K and (b) their corresponding pore-size distribution curve of U-SnO and UH-SnO.

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Fig. S3 (a,c) Cycle life of UH-SnO, the pure substrate of graphite sheet and Ti foil at 0.4 A g^{-1} with the voltage range from -0.3 to 1.2 V, (b,d) the long cycle performance of graphite sheet and Ti foil.